NSN 5961-01-315-4954

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-315-4954 **Inclosure Material:** Plastic **Overall Length:** 0.370 inches **Terminal Length:** 1.100 inches **Overall Diameter:** 0.200 inches **Function For Which Designed:** Transient suppressor **End Application:** 6625-01-125-3775 meter, impedance **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 9.0 breakdown voltage, dc and 11.0 breakdown voltage, dc **Current Rating Per Characteristic:** 1.00 milliamperes drain current nanoamperes **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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